## NSN 5961-01-299-8456

**Demilitarization:** 

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-299-8456 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.350 inches and 0.370 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-39 **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Burn in and electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 15.0 forward gate to source voltage and -0.3 reverse gate to source voltage **Current Rating Per Characteristic:** 2.00 amperes drain current and 2.00 milliamperes forward gate current and 100.00 milliamperes reverse gate current with all other terminals short-circuit to source, junction-gate **Power Rating Per Characteristic:** 8.33 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**